

CGHV59070F/P

Rev. V1

#### **Features**

- 4.4 5.9 GHz Operation
- 70 W Minimum Output Power
- Large Signal Gain: 14 dB
- Drain Efficiency: 55 %
- Internally Matched

## **Applications**

- Wireless Infrastructure
- Marine Radar
- · Weather Monitoring
- Air Traffic Control
- Maritime Vessel Traffic Control
- Port Security
- Troposcatter Communications
- Beyond Line of Sight BLOS

## **Description**

The CGHV59070 is an internally matched gallium nitride (GaN) amplifier. The CGHV59070, operating from a 50 Volt rail, offers a general purpose, broadband solution to a variety of RF and microwave applications. The good efficiency, high gain and wide bandwidth capabilities make the CGHV59070 ideal for linear applications such as wireless infrastructure and for compressed amplifier circuits. The amplifier is available in a flange and pill package.

# **Typical RF Performance:**

Measured in Evaluation Test Fixture<sup>1</sup> at  $P_{IN} = 35.5$  dBm, 100 µsec pulse width and 10% Duty Cycle.

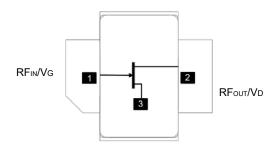
• 
$$V_{DS} = 50 \text{ V}, I_{DQ} = 150 \text{ mA}, T_{C} = 25^{\circ}\text{C}$$

Frequency (GHz)	Output <sup>1</sup> Power <sup>1</sup> Power Gain (W) (dB)		η <sub>□</sub> ¹ (%)
4.8	84	13.7	55
5.0	93	14.2	56
5.2	101	14.5	57
5.4	102	14.6	56
5.6	95	14.3	54
5.8	84	13.7	50
5.9	76	13.3	48

1. Performance values and curves in this data sheet were measured in this fixture.



#### **Functional Schematic**



## **Pin Configuration**

Pin#	Pin Name	Function
1	RF <sub>IN</sub> / V <sub>G</sub>	RF Input / Gate
2	RF <sub>OUT</sub> / V <sub>D</sub>	RF Output / Drain
3	Flange <sup>2</sup>	Ground / Source

<sup>2.</sup> The flange on the package bottom must be connected to RF, DC and thermal ground.

## **Ordering Information**

Part Number	MOQ Increment
CGHV59070F	Bulk
CGHV59070P	Bulk
CGHV59070F-AMP	Sample Board

<sup>\*</sup> Restrictions on Hazardous Substances, compliant to current RoHS EU



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# RF Electrical Specifications: $T_A = +25$ °C, $V_{DS} = 50$ V, $I_{DQ} = 150$ mA

Parameter	Units	Min.	Тур.	Max.	Conditions
Small Signal Gain at f = 5.2 GHz	dB	15.5	17	_	V <sub>dd</sub> = 50 V, I <sub>dq</sub> = 150 mA, P <sub>in</sub> = 10 dBm
Output Power at f = 5.2 GHz	W	75.9	100	_	
Output Power at f = 5.55 GHz	W	75.9	100	_	
Output Power at f = 5.9 GHz	W	62.4	77	_	
Power Gain at f = 5.2 GHz	dB	_	14.5	_	$V_{dd}$ = 50 V, $I_{dq}$ = 150 mA, $P_{in}$ = 35.5 dBm Pulse Width = 100 $\mu$ s, Duty Cycle = 10%
Drain Efficiency at f = 5.2 GHz	%	50	54	_	
Drain Efficiency at f = 5.55 GHz	%	46	55	_	
Drain Efficiency at f = 5.9 GHz	%	40	48	_	
Ruggedness: Output Mismatch	Ψ	_	_	5:1	No damage at all phase angles, $V_{dd}$ = 50 V, $I_{dq}$ = 150 mA, $P_{in}$ = 35.5 dBm Pulse width = 100 µs, Duty Cycle = 10%

# DC Electrical Characteristics T<sub>A</sub> = 25°C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Drain-Source Leakage Current	V <sub>GS</sub> = -8 V, V <sub>DS</sub> = 150 V	I <sub>DLK</sub>	-	-	4.16	mA
Gate-Source Leakage Current	V <sub>GS</sub> = -8 V, V <sub>DS</sub> = 10 V	I <sub>GLK</sub>	-1.45	-	-	mA
Gate Threshold Voltage	$V_{DS} = 10 \text{ V}, I_{D} = 10.4 \text{ mA}$	V <sub>T</sub>	-3.8	-2.8	-2.3	<b>V</b>
Gate Quiescent Voltage	V <sub>DS</sub> = 50 V, I <sub>D</sub> = 150 mA	$V_{GSQ}$	-	-2.7	-	V



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# **Absolute Maximum Ratings**<sup>1,2</sup>

Parameter	Absolute Maximum		
Drain-Source Voltage	150 V		
Gate Voltage	-10, +2 V		
Storage Temperature	-65°C to +150°C		
Junction Temperature <sup>4,5,6</sup>	+225°C		
Gate Current	10.4 mA		
DC Drain Current	6.3 A		
Mounting Temperature <sup>3</sup>	+245°C		
Operating Temperature	-40°C to +125°C		

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- MACOM does not recommend sustained operation near these survivability limits.
- 3. Mounting temperature for 30 seconds.
- 4. Operating at nominal conditions with  $T_J \le +225$  C will ensure MTTF > 1 x  $10^6$  hours.
- 5. Junction Temperature ( $T_J$ ) =  $T_C$  +  $\Theta$ jc \* (V \* I)

  Typical thermal resistance ( $\Theta$ jc) = 2.99 °C/W for CW.

  a) For  $T_C$  = +55°C,  $T_J$  = 225 °C @  $P_{diss}$ = 57 W
- 6. Junction Temperature  $(T_J) = T_C + \Theta jc * (V * I)$

Typical thermal resistance (Θjc) = 0.85 °C/W for 100μs, 10%.

a) For 
$$T_C$$
 = +85°C,  
 $T_J$  = 145 °C @  $P_{diss}$ = 70 W

#### **Handling Procedures**

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

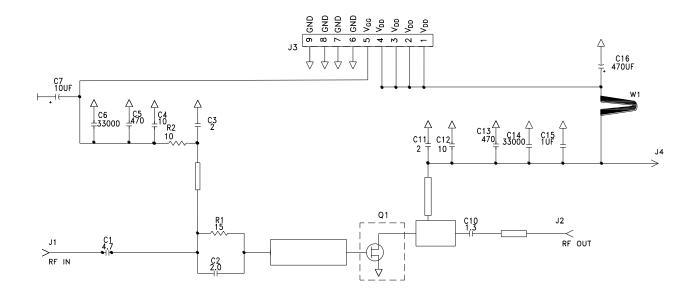
These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.



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#### Evaluation Test Fixture and Recommended Tuning Solution, 5.2—5.9 GHz



# **Description**

Parts measured on evaluation board (20-mil thick RF-35). Matching is provided using a combination of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

## **Biasing Sequence**

#### **Bias ON**

- 1. Ensure RF is turned off
- 2. Apply pinch-off voltage of -5 V to the gate
- 3. Apply nominal drain voltage
- 4. Bias gate to desired quiescent drain current
- 5. Apply RF

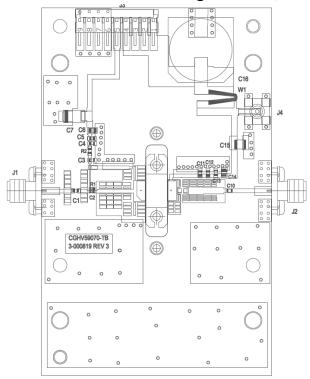
#### **Bias OFF**

- 1. Turn RF off
- 2. Apply pinch-off voltage of -5 V to the gate
- 3. Turn-off drain voltage
- 4. Turn-off gate voltage



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# **Evaluation Test Fixture and Recommended Tuning Solution, 5.2 - 5.9 GHz**



# **Assembly Parts List**

Reference Designator	Description	Qty
R1	RES, 15,OHM, +/- 1%, 1/16W, 0402	1
R2	RES,1/16W,0603,1%,10.0 OHMS	1
C1	CAP, 4.7 pF,+/-0.1pF, 0603, ATC600S	2
C10	CAP, 1.3 pF,+/-0.1pF, 0603, ATC600S	1
C3,C11	CAP, 2.0 pF,+/-0.1pF, 0603, ATC600S	2
C2	CAP, 2.0 pF, +/- 0.05 pF, 0402, ATC	1
C4,C12	CAP, 10pF,+/-5%, 0603, ATC	2
C5,C13	CAP, 470PF, 5%, 100V, 0603, X	2
C6,C14	CAP,33000PF, 0805,100V, X7R	2
C15	CAP, 1.0UF, 100V, 10%, X7R, 1210	1
C7	CAP 10UF 16V TANTALUM	1
C16	CAP, 470uF, 20%, 80V, ELECT, SMD Size K	1
J1,J2	CONN, SMA, PANEL MOUNT JACK, FLANGE, 4- HOLE, BLUNT POST, 20MI	2
J3	HEADER RT>PLZ .1CEN LK 9POS	1
J4	CONNECTOR; SMB, Straight, JACK,SMD	1
W1	CABLE, 18 AWG, 4.2"	1
-	PCB, TEST FIXTURE, TACONIC RF35, 20 MIL	1
Q1	CGHV59070F/P	1

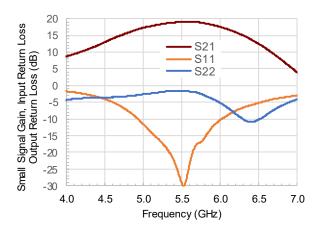


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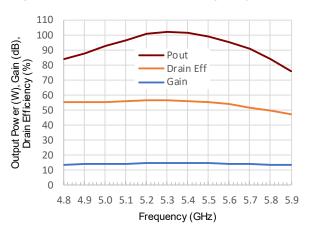
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Typical Performance Curves as Measured in the 5.2 – 5.9 GHz Evaluation Test Fixture Pulse width = 100  $\mu$ s, Duty Cycle = 10%,  $P_{IN}$  = 35.5 dBm,  $V_{DS}$  = 50 V,  $I_{DQ}$  = 150 mA (Unless otherwise noted) For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

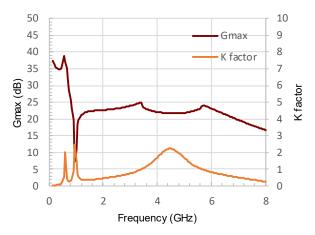
#### S11, S21, & S22 vs. Frequency



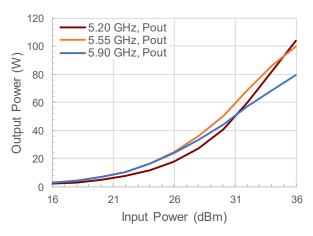
#### Output Power, Gain and PAE vs. Frequency



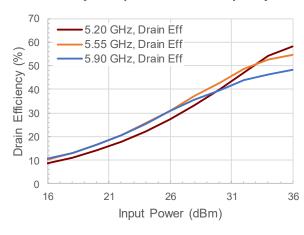
#### Maximum Available Gain and K Factor vs. Frequency



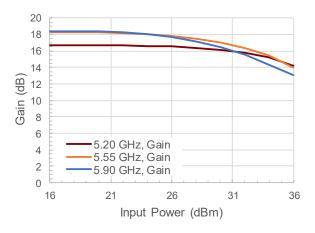
Output Power vs. Input Power and Frequency



#### Drain Efficiency vs. Input Power and Frequency



Gain vs. Input Power and Frequency



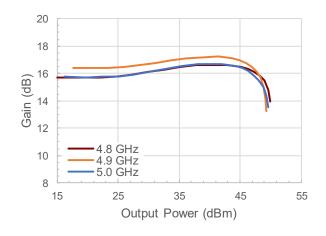


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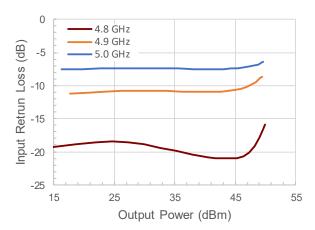
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Typical Performance Curves as Measured in the 4.8 – 5.0 GHz Evaluation Test Fixture WCDMA, 7.5 dB PAR Signal,  $P_{IN}$  = 42 dBm,  $V_{DS}$  = 50 V,  $I_{DQ}$  = 75 mA (Unless otherwise noted) For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

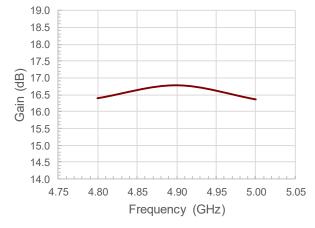
#### Power Gain vs. Output Power



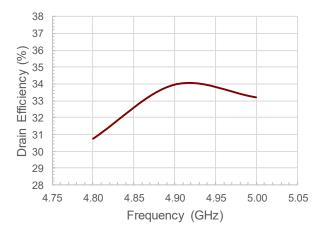
#### Input Power vs. Output Power



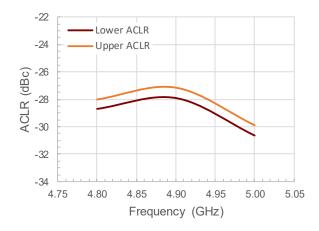
#### Power Gain vs. Frequency



#### Drain Efficiency vs. Frequency



#### ACLR vs. Frequency

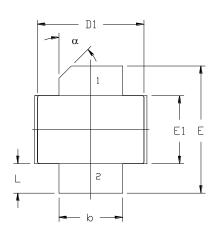


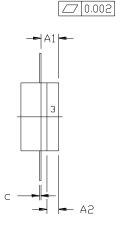


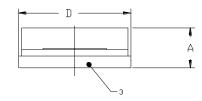
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## Lead-free 440170 Package Dimensions







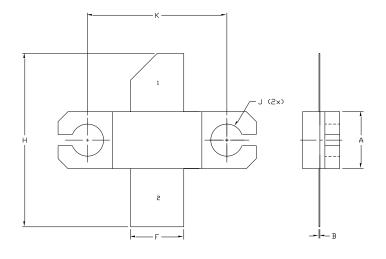
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M 1994.
- 2. CONTROLLING DIMENSION: INCH.
- 3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020° BEYOND EDGE OF LID.
- 4. LID MAY BE MISALIGNED TO THE BODY OF PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.

	INCHES		MILLIMETERS		NOTES	
DIM	MIN	MAX	MIN	MAX		
Α	0.125	0.145	3.18	3.68		
A1	0.057	0.067	1.45	1.70		
A2	0.035	0.045	0.89	1.14		
b	0.210	0.220	5.33	5.59	2×	
С	0.004	0.006	0.10	0.15	2×	
D	0.375	0.385	9.53	9.78		
D1	0.355	0.365	9.02	9.27		
Ε	0.400	0.460	10.16	11.68		
E1	0.225	0.235	5.72	5.97		
L	0.085	0.115	2.16	2.92	2×	
α	45° REF		45° REF			

- PIN 1. GATE
  - 2. DRAIN
  - 3. SOURCE

NOTES:

## Lead-free 440224 Package Dimensions



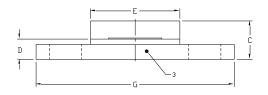
4. LID MAY BE MISALIGNED TO THE BODY OF THE PACKAGE BY A MAXIMUM OF 0.008' IN ANY DIRECTION. 5. ALL PLATED SURFACES ARE NI/AU INCHES MILLIMETERS DIM MIN MAX MIN MAX Α 0.225 0.235 5.72 5.97 0.004 0.006 0.10 0.15 0.145 0.165 3.18 4.19 0.077 0.087 1.96 0.355 0.365 9.02 9.27 0.210 0.220 5.33 5.59

1. DIMENSIONING AND TOLERANICING PER ANSI Y14.5M, 1982.

3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020\* BEYOND EDGE OF LID.

2. CONTROLLING DIMENSION: INCH.

0.795 0.805 20.19 20.45 0.670 0.730 17.02 18.54 ø .130 3.30 0.562 14.28





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